

Discovery of Hidden Dimensions in Information Space and Ultra-High Density Memory

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Introduction

- Moore's Law has resulted in truly remarkable information density but scaling is both incredibly expensive and extremely challenging
- We developed a technique to store orders of magnitude more data per device using only standard resistive memory devices.

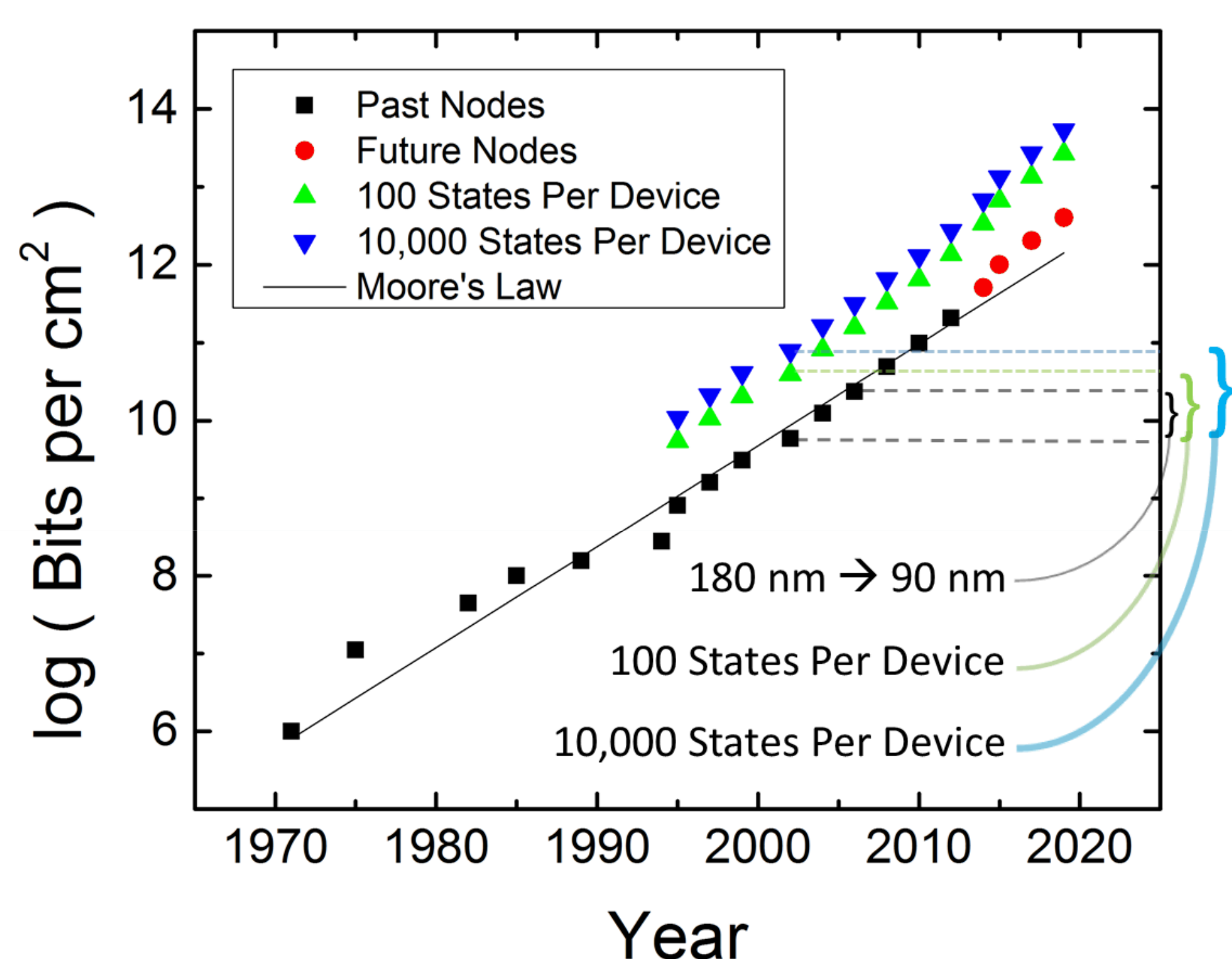


Fig 1: A logarithmic plot shows scaling of bit density for Moore's Law and Multi-dimensional Information Space

- At the level we have already demonstrated, we can add ~7 years to Moore's law for memory and we expect 10 years is reasonable.
- The approach is based on expanding information storage into higher dimensions by electrically tuning the filament properties.

Hidden Dimensions

- Digital memory is 0-dimensional like a point in space. Some memories are now 1-dimensional over a small range (i.e. Resistance = 1,2,3).

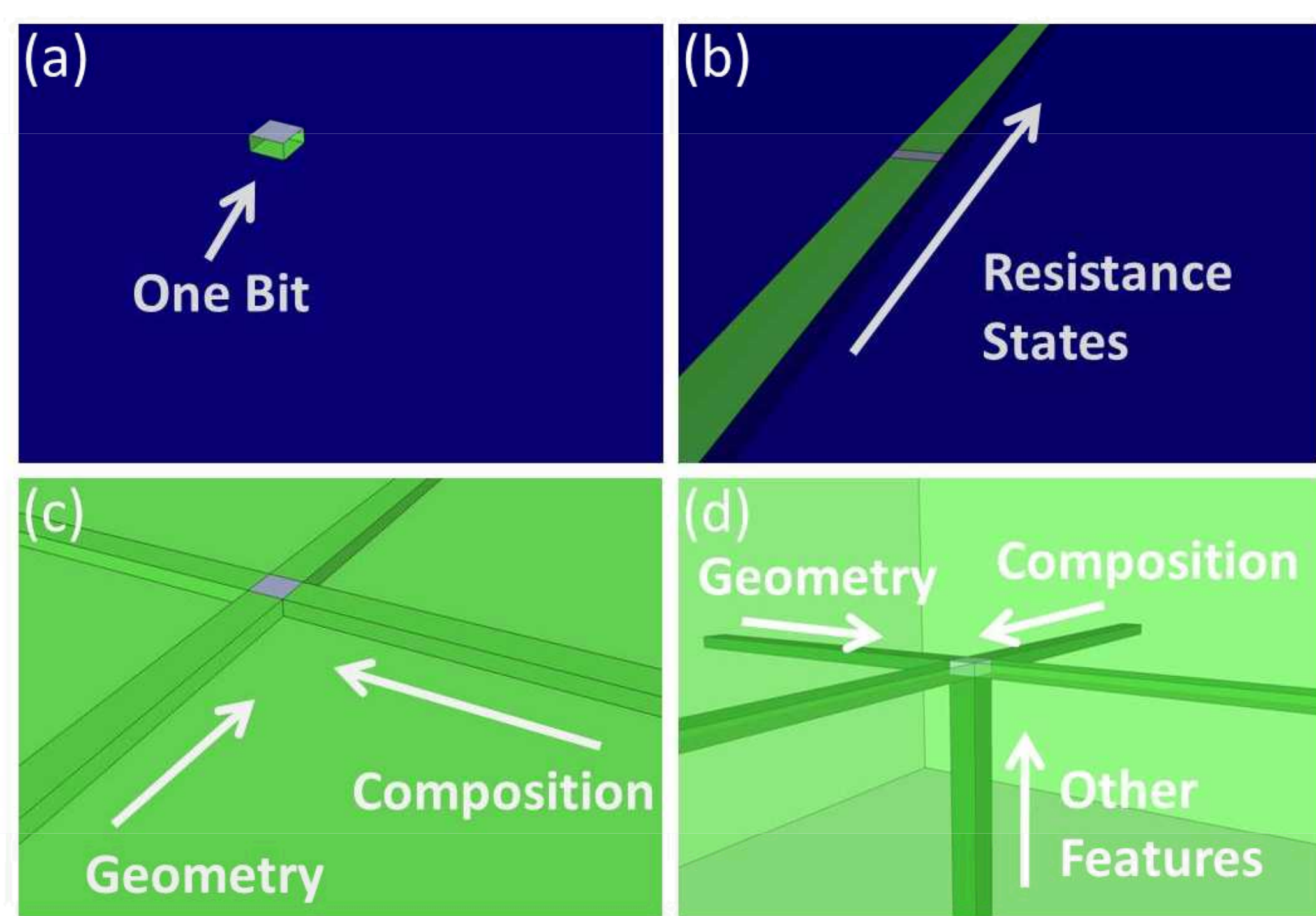


Fig 2: Information space depicted for (a) digital, (b) multi-level cell, (c) 2-dimensional, and (d) many-dimensional devices.

- Since resistance depends on radius and conductivity, and we can control both, we can make two dimensional information space.

Reading and Writing: 2-D

- Positive polarity sets the radius and negative sets the conductivity
- Power and resistance are more useful coordinates than I-V.

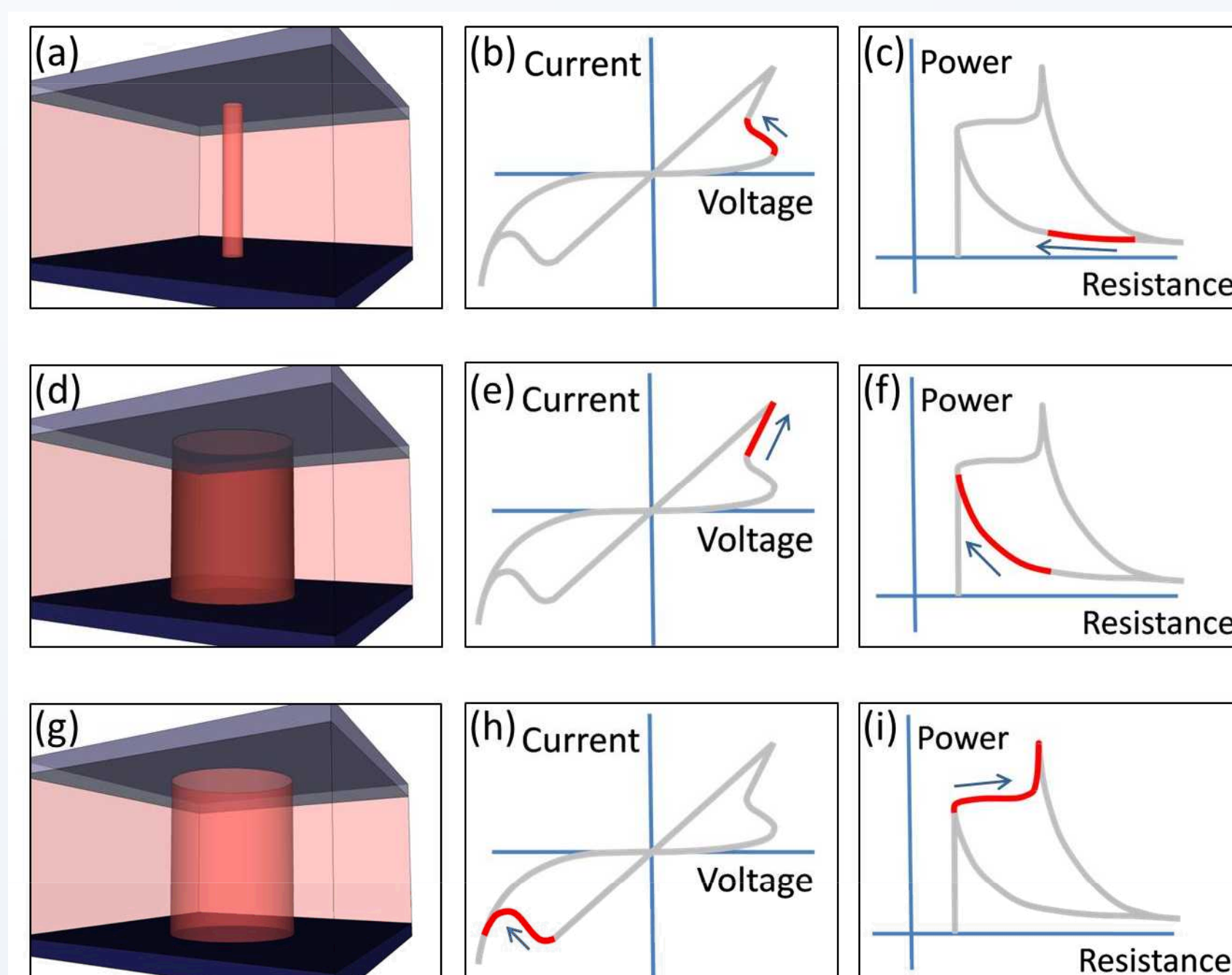


Fig 3: The radius and conductivity can be controlled separately by selecting electrical polarity. Power-resistance are particularly useful coordinates.

- To read the state, the resistance is measured, then the power required to change resistance is measured, giving 2 dimensions.

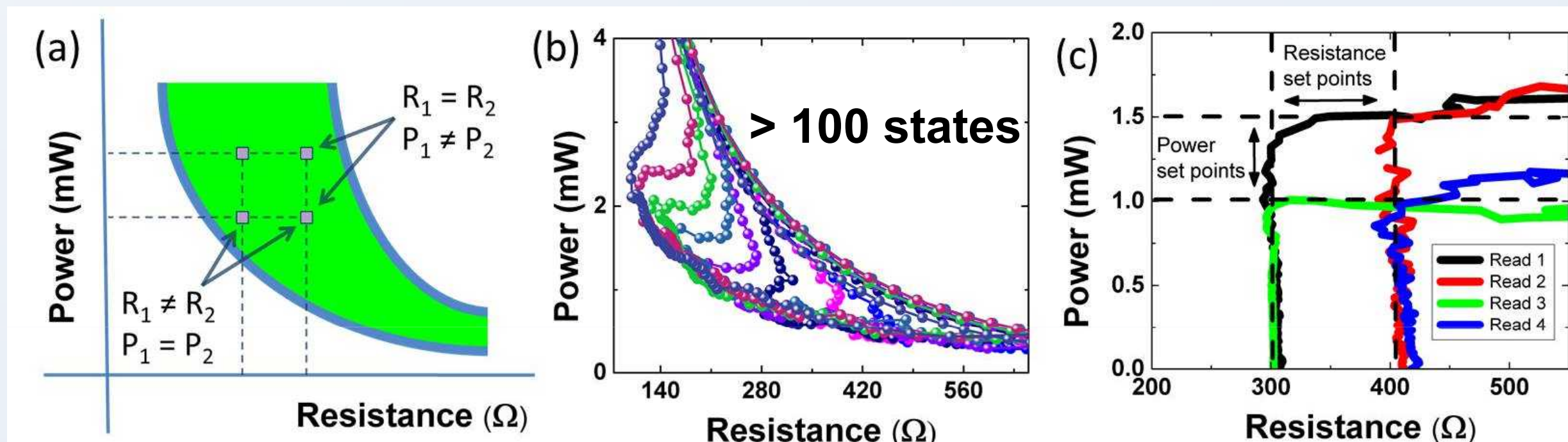


Fig 4: 2-dimensional information space in power-resistance coordinates is depicted and experimentally demonstrated for write and read.

The Third Dimension

- By changing the geometry away from cylinders it is possible to make at least one more dimension.

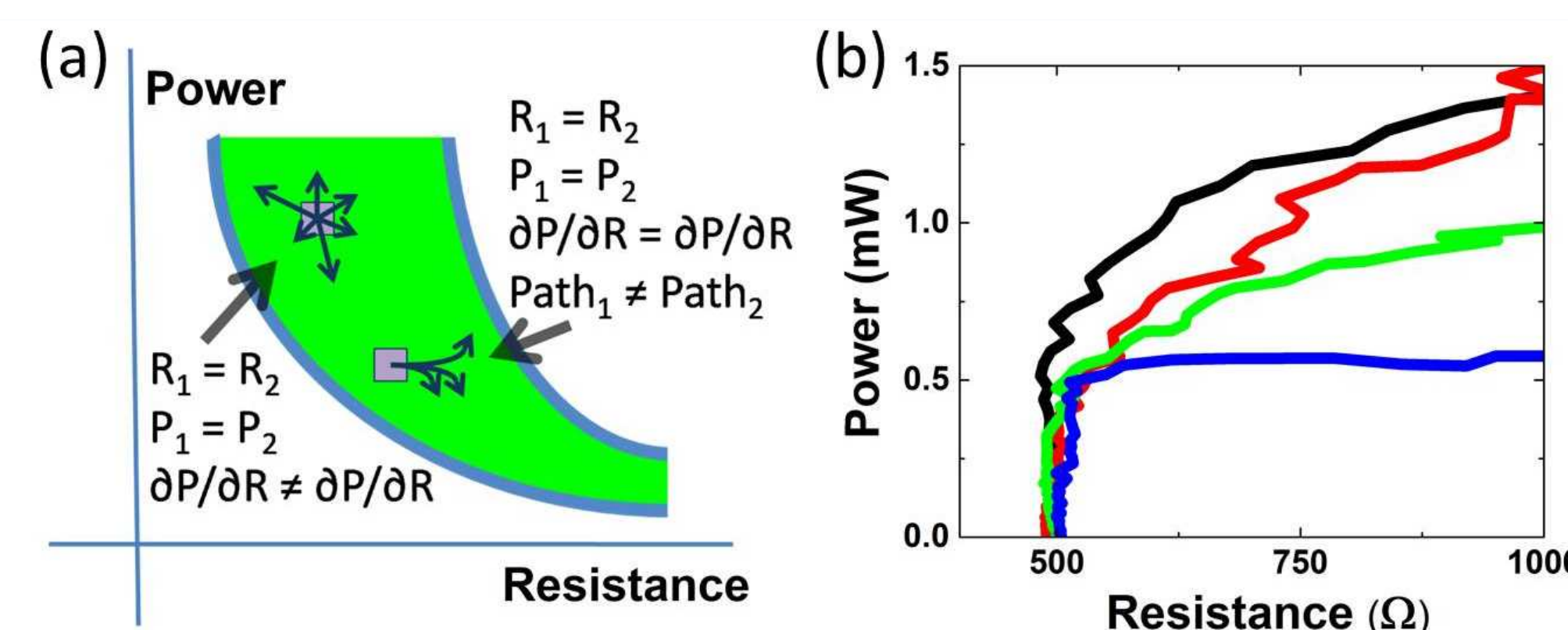


Fig 5: A third dimension (and probably more) exists using the slope at every point in power-resistance space.

Summary

- Hidden dimensions add ~ 7-10 years to Moore's Law for memory.
- This approach can be implemented rapidly because it uses only standard devices already in development.